

# **AW302A Datasheet**

**Zhuhai Jieli Technology Co.,LTD**

**Version 1.0**

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Revision History

Date	Revision	Description
2024.02.28	V1.0	Initial Release

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# AW302A Features

## SYSTEM

- 32bit DSP 240MHz
- Support AES128
- I-cache
- Support EMU
- On-chip SRAM 80kbyte
- Support MPU
- Built-In Flash
- 24MHz crystal oscillator
- Internal RC oscillator, PLL

## DSP Audio Processing

- SBC/SPEEX/OPUS/MP2/UMP3/MP3/MIDI/F1 A/ADPCM/A codec
- mSBC voice codec

## Audio

- 1 x 16bit DAC
  - ❖ SNR 90dB
  - ❖ Noise 18uVrms
  - ❖ Sampling rate 8~96kHz
- 1 x 16bit ADC
  - ❖ SNR 91dB
  - ❖ Sampling rate 8~48kHz
- 1 x 16bit Class-D Speaker Driver
  - ❖ SNR 98dB
  - ❖ Sampling rate 32~48kHz
  - ❖ Drive speaker directly 320mW @ 8Ω
- I<sup>2</sup>S interface

## Bluetooth

- BLE5.4 +2.4GHz-Proprietary (QDID 223418)
- Support AoA Transmitter
- Support long range BLE
- Maximum transmitting power 6dBm
- Receiver sensitivity
  - ❖ -95dBm @BLE-1Mbps
  - ❖ -93dBm @BLE-2Mbps
  - ❖ -99dBm @BLE-S2
  - ❖ -104dBm @BLE-S8

## Peripherals

- 1 x Full speed USB
- 1 x SD host controller
- 4 x Multi-function 16bit timer
- 3 x UART interface
- 1 x I<sup>2</sup>C Master/Slave interface
- 3 x SPI Master/Slave interface
- 1 x 12bit 1Msps ADC(5 Channel)
- 7 x GPIO Support function remapping
- 1 x CAN controller
- 6 x MCPWM

## PMU

- VPWR range 2.7V to 5.5V
- IOVDD range 1.8V to 3.6V

## Packages

- SOP16

## Temperature

- Operating temperature
  - TC = -20℃ to +85℃ (standard range)
  - TC = -40℃ to +105℃ (extended range)
- Storage temperature -65℃ to +150℃

## Applications

- Bluetooth TV remote controller
- Bluetooth intercom

## 1 Block Diagram

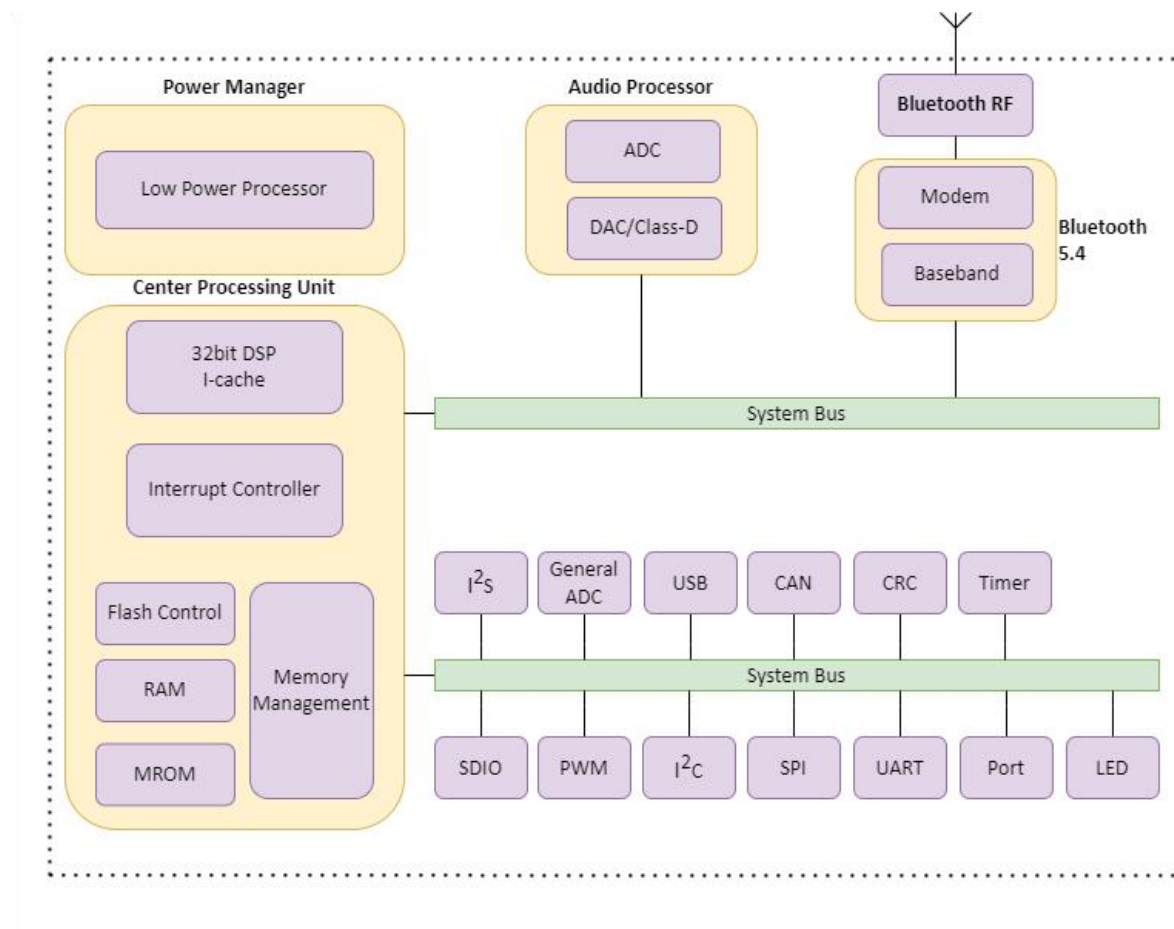


Figure 1-1 AW302A Block Diagram

### Figure 2-1 AW302A Pin Assignment

## 2.2 Pin Description

Table 2-2-1 AW302A Pin Description

Pin No.	Name	Type	IO Initial State	Description
1	VSS	G	--	Ground
2	BTRF	RF	--	Bluetooth RF Antenna
3	XOSCI	I	--	Crystal Oscillator Input
4	XOSCO	O	--	Crystal Oscillator Output
5	PA14	I/O	Z	ADC4(ADC Input Channel 4) SPI0_DOB(0)
6	PA13	I/O	Z	ADC3(ADC Input Channel 3) SPI0_CLKB
7	USBDM	I/O	15kΩ Pull-down	ADC7(ADC Input Channel 7)
8	USBDP	I/O	15kΩ Pull-down	ADC6(ADC Input Channel 6)
9	AVSS	G	--	AUDIO Ground
10	PA7	I/O	Z	AIN_AP4(Audio ADC Positive Input) MICBIASC(MIC Bias Output)
11	PA5	I/O	Z	ADC1(ADC Input Channel 1) AIN_AP2(Audio ADC Positive Input) DAC Output
12	PB6	I/O	Z	--
	APAN	O	Z	Class-D Speaker Driver Negative Output
13	PB5	I/O	Z	--
	APAP	O	Z	Class-D Speaker Driver Positive Output
14	VPWR	P	--	Charge Power Input
15	IOVDD	P	--	IO Power
16	PA0	I/O	15kΩ Pull-down	--

### Note

- 1.IO initial state abbreviations Z--High resistance, H--High level, L--Low level, X--May be changed during power on.
- 2.Timer, MCPWM, UART, I<sup>2</sup>C, I<sup>2</sup>S, SPI1/2, SD, CAN functions can be remapped to any I/O.

Table 2-2-2 Pin Types Description

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
G	Ground	I	Input
RF	RF antenna	O	Output

## 3 Electrical Characteristics

### 3.1 Absolute Maximum Ratings

Table 3-1 Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
T <sub>opt</sub>	Operating temperature	-20	+85	°C
T <sub>stg</sub>	Storage temperature	-65	+150	°C
VPWR	Supply Voltage	-0.3	6.0	V
IOVDD		-0.3	3.6	V
GPIO	Input voltage of GPIO (except PA0/PB5/PB6)	-0.3	3.6	V
HVTIO	Input voltage of HVT-IO (PA0/PB5/PB6)	-0.3	6.0	V

#### Note

1.Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device.

### 3.2 ESD Ratings

Table 3-2 ESD Ratings

Parameter	Typ	Test pin	Reference standard
Human Body Mode	±4kV	All pins	JEDEC EIA/JESD22-A114
Machine Mode	±200V	All pins	JEDEC EIA/JESD22-A115
Charge Device Model	±2kV	All pins	ANSI/ESDA/JEDEC JS-002-2022

### 3.3 PMU Characteristics

Table 3-3-1 PMU Characteristics under VPWR supply

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
VPWR	Power supply	--	2.7	--	5.5	V
Operating mode						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
IOVDD	Voltage output	--	--	3.0	--	V
	Loading current	IOVDD=3.0V@VPWR = 3.7V	--	--	120	mA
Low Power mode						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
IOVDD	Loading current	IOVDD=3.0V@VPWR = 3.7V	--	--	10	mA

Table 3-3-2 PMU Characteristics under IOVDD supply

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
IOVDD	Power supply	--	1.8	--	3.6	V



### 3.4 IO Characteristics

Table 3-4 IO Characteristics

Input Characteristics						
Symbol	Parameter	Conditions	IO	Min	Max	Unit
V <sub>IL</sub>	Low-Level Input Voltage	IOVDD = 3.0V	PA0,PA5,PA7 PA13,PA14 PB5,PB6 USBDP USBDM	-0.3	1.4	V
V <sub>IH</sub>	High-Level Input Voltage	IOVDD = 3.0V	PA5,PA7 PA13,PA14 USBDP USBDM	1.7	3.3	V
		IOVDD = 3.0V	PA0 PB5 PB6	1.7	5.5	V
Output Characteristics						
Symbol	Parameter	Conditions	IO	Typ	Unit	
I <sub>OL</sub>	Output Current	IOVDD = 3.0V Voutput = 0.3V	PA5,PA7 PA13,PA14	3(HD=0) 9(HD=1) 21(HD=2) 54(HD=3)	mA	
		IOVDD = 3.0V Voutput = 0.3V	PA0 PB5 PB6 USBDP USBDM	8	mA	
I <sub>OH</sub>	Output Current	IOVDD = 3.0V Voutput = 2.7V	PA5,PA7 PA13,PA14	3(HD=0) 9(HD=1) 21(HD=2) 54(HD=3)	mA	
		IOVDD = 3.0V Voutput = 2.7V	PA0 PB5 PB6 USBDP USBDM	8	mA	
Internal Resistance Characteristics						
Symbol	Parameter	Conditions	IO	Typ	Unit	
R <sub>pu</sub>	Pull-up Resistance	IOVDD = 3.0V	PA0,PA5,PA7 PA13,PA14 PB5,PB6	10k(PU=1) 100k(PU=2) 1M(PU=3)	Ω	
		IOVDD = 3.0V	USBDP	1.5k	Ω	

		IOVDD = 3.0V	USBDM	180k	Ω
Symbol	Parameter	Conditions	IO	Typ	Unit
R <sub>pd</sub>	Pull-down Resistance	IOVDD = 3.0V	PA0,PA5,PA7 PA13,PA14 PB5,PB6	10k(PD=1) 100k(PD=2) 1M(PD=3)	Ω
		IOVDD = 3.0V	USBDP USBDM	15k	Ω

**Note**

1.Internal pull-up/pull-down resistance accuracy  $\pm 20\%$ .

### 3.5 Audio DAC Characteristics

Table 3-5 Audio DAC Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Resolution	--	--	16	--	bits
Output Sample Rate	--	8	--	96	kHz
SNR	Single-ended Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=100kΩ	--	90	--	dB
Dynamic Range	Single-ended Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=100kΩ	--	90	--	dB
THD+N	Single-ended Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=100kΩ	--	-83	--	dB
Noise Floor	Single-ended Mode B/W=20Hz~20kHz A-Weighted Load=100kΩ	--	18	--	uVrms
Max Amplitude	Single-ended Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=100kΩ THD+N < 0.1%	--	0.6	--	Vrms

### 3.6 Audio ADC Characteristics

Table 3-6 Audio ADC Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Resolution	--	--	16	--	bits
Input Sample Rate	--	8	--	48	kHz
SNR	Single-ended Input Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted ADC Gain=0dB	--	91	--	dB
Dynamic Range	Single-ended Input Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted ADC Gain=0dB	--	91	--	dB
THD+N	Single-ended Input Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted ADC Gain=0dB	--	-80	--	dB
Analogue Gain	--	-6	--	21	dB
Max Input Level	Single-ended Input Mode ADC Gain=0dB	--	1	--	Vrms

### 3.7 Class-D Speaker Driver Characteristics

Table 3-7 Class-D Speaker Driver Characteristics under HPVDD 3.7V

Parameter	Conditions	Min	Typ	Max	Unit
SNR	Differential Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=10kΩ	--	98	--	dB
	Differential Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=8Ω	--	98	--	dB
THD+N	Differential Mode Fin=1kHz@0dBFS Fs=44.1kHz	--	-73	--	dB

Parameter	Conditions	Min	Typ	Max	Unit
	B/W=20Hz~20kHz A-Weighted Load=10kΩ				
	Differential Mode Fin=1kHz@0dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=8Ω	--	-37	--	dB
Noise Floor	Differential Mode B/W=20Hz~20kHz A-Weighted Load=10kΩ	--	30	--	uVrms
	Differential Mode B/W=20Hz~20kHz A-Weighted Load=8Ω	--	20	--	uVrms
Dynamic Range	Differential Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=10kΩ	--	88	--	dB
	Differential Mode Fin=1kHz@-60dBFS Fs=44.1kHz B/W=20Hz~20kHz A-Weighted Load=8Ω	--	88	--	dB

### 3.8 12bit ADC Characteristics

Table 3-8 12bit ADC Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
AVDD(ADC Supply Voltage)	AVDD=IOVDD	1.8	3	3.3	V
f <sub>ADC</sub> (ADC Clock Frequency)	--	0.25	--	14	MHz
T <sub>s</sub> (ADC Sampling Time)	--	1.5	--	--	1/f <sub>ADC</sub>
ADC Conversion Time	Including Sampling Time	8	--	14	1/f <sub>ADC</sub>
ADC Input Voltage Range	--	0	--	AVDD	V
ADC Internal Sample and Hold Capacitor	--	--	5	--	pF
Sampling Switch Resistance	--	--	--	1	kΩ
External Input Impedance	T <sub>s</sub> =1.5/f <sub>ADC</sub>	--	--	1.5	kΩ
	T <sub>s</sub> >=50/f <sub>ADC</sub>	--	--	50	kΩ
ADC Resolution	Programmable	6	12	12	bit
INL	AVDD=3V, f <sub>ADC</sub> =14MHz	--	±2	--	LSB
DNL	AVDD=3V, f <sub>ADC</sub> =14MHz	--	±1	--	LSB

Parameter	Conditions	Min	Typ	Max	Unit
ADC Offset Error	AVDD=3V, $f_{ADC}=14\text{MHz}$	--	3	--	LSB
Gain Error	AVDD=3V, $f_{ADC}=14\text{MHz}$	--	3	--	LSB
Current Consumption in Conversion Mode	Single-ended, $f_{ADC}=14\text{MHz}$	--	350	--	$\mu\text{A}$

## 3.9 BT Characteristics

### 3.9.1 Transmitter

Table 3-9-1 Transmitter characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Maximum RF Transmit Power	BLE-1Mbps	--	0	6	dBm

### 3.9.2 Receiver

Table 3-9-2 Receiver characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Sensitivity	BLE-1Mbps	--	-95	--	dBm
	BLE-2Mbps	--	-93	--	dBm
	BLE-S2	-99	-98	--	dBm
	BLE-S8	-104	-103	--	dBm

## 4 Package Information

### 4.1 SOP16

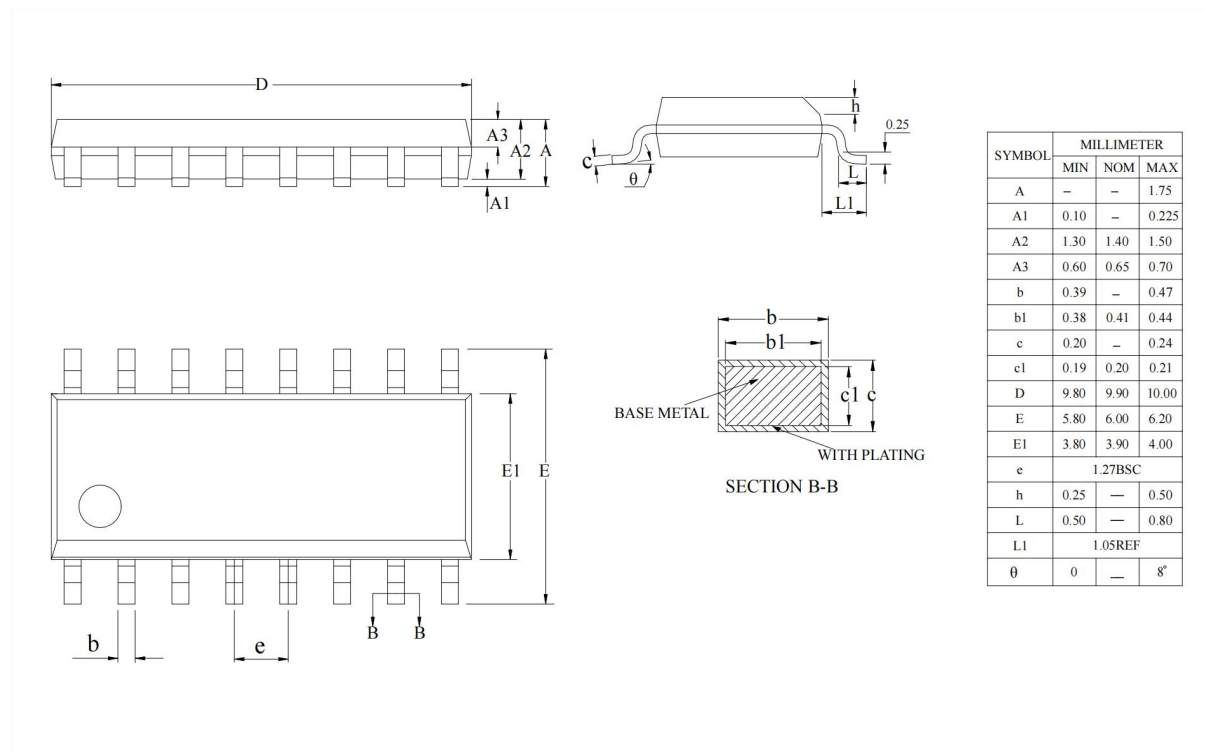


Figure 4-1 AW302A Package

## 5 IC Marking Information

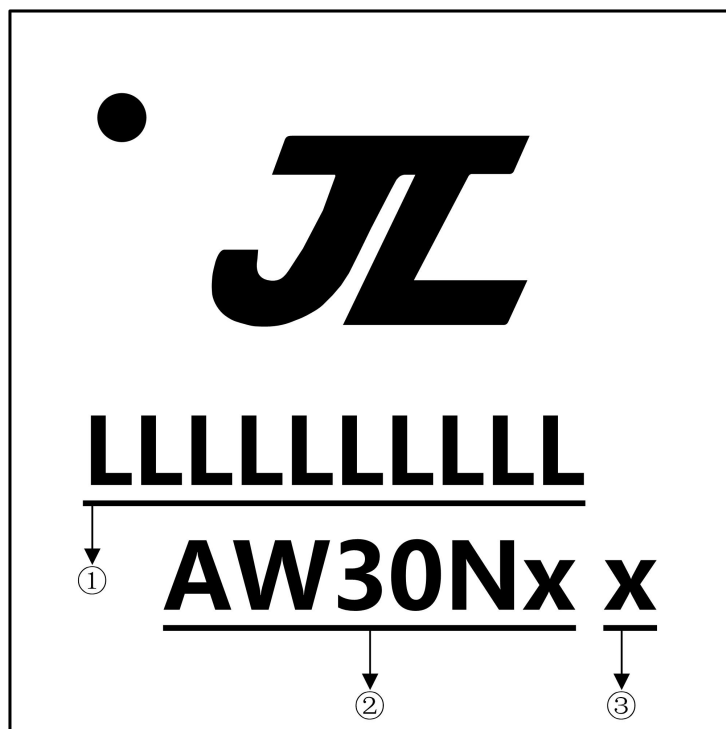


Figure 5-1 AW302A Package Outline

- ① LLLLLLLLLL Production Batch
- ② AW30Nx Chip Model
- ③ x Built-in flash size
  - 0 No Flash Memory
  - 2 2Mbit Flash
  - 4 4Mbit Flash

## 6 Solder-Reflow Condition

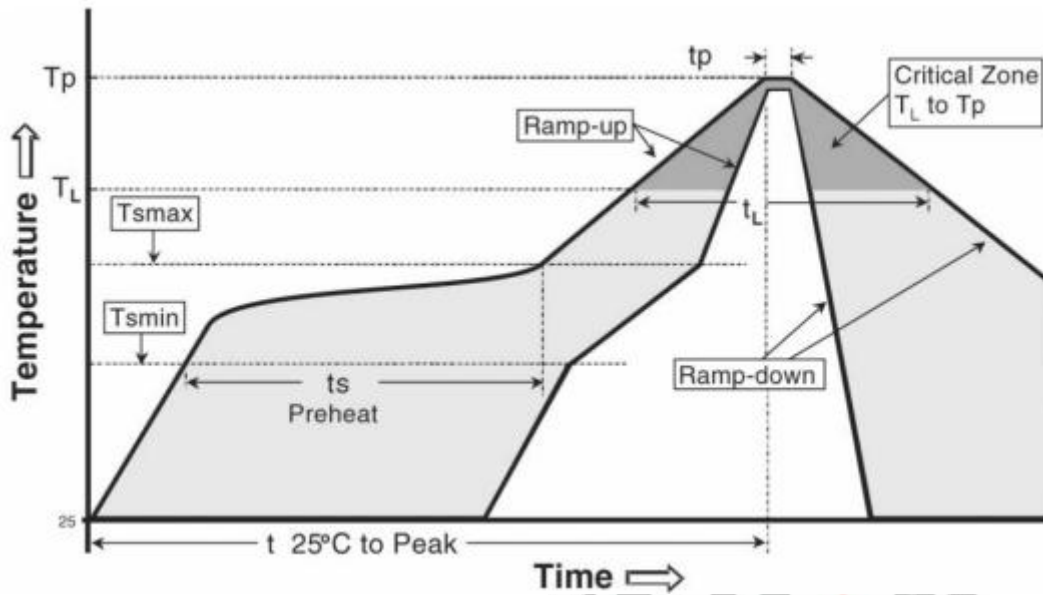


Figure 6-1 Classification Reflow Profile

Table 6-1 Classification Profiles

Profile Feature		Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat/Soak	Temperature Min ( $T_{smin}$ )	100°C	150°C
	Temperature Max ( $T_{smax}$ )	150°C	200°C
	Time ( $t_s$ ) from ( $T_{smin}$ to $T_{smax}$ )	60-120 seconds	60-180 seconds
Average ramp-up rate ( $T_{smax}$ to $T_p$ )		3°C/second max	3°C/second max
Liquidus temperature ( $T_L$ )		183°C	217°C
Time ( $t_L$ ) maintained above $T_L$		60-150 seconds	60-150 seconds
Peak package body temperature ( $T_p$ )		See Table 6-2	See Table 6-3
Time within 5°C of actual Peak Temperature ( $t_p$ ) <sup>2</sup>		10-30 seconds	20-40 seconds
Ramp-down rate ( $T_p$ to $T_L$ )		6°C/second max	6°C/second max
Time 25°C to peak temperature		6 minutes max	8 minutes max

**Note**

- 1.All temperatures refer to topside of the package, measured on the package body surface
- 2.Time within 5°C of actual peak temperature ( $t_p$ ) specified for the reflow profiles is a “supplier” and “user” maximum.

Table 6-2 SnPb Classification Temperature

Package Thickness	Volume mm <sup>3</sup> < 350	Volume mm <sup>3</sup> ≥ 350
<2.5 mm	240 +0/-5°C	225 +0/-5°C
≥2.5 mm	225 +0/-5°C	225 +0/-5°C



**Table 6-3 Pb-free - Classification Temperature**

Package Thickness	Volume mm <sup>3</sup> < 350	Volume mm <sup>3</sup> 350 - 2000	Volume mm <sup>3</sup> > 2000
< 1.6mm	260℃	260℃	260℃
1.6 mm - 2.5mm	260℃	250℃	245℃
> 2.5mm	250℃	245℃	245℃

**Note**

1.\*Tolerance The device manufacturer/supplier shall assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0℃.For example 260℃+0℃)at the rated MSL level.